

Elucidating the surface reaction of a-Si thin film used as model electrode for Li-ion batteries

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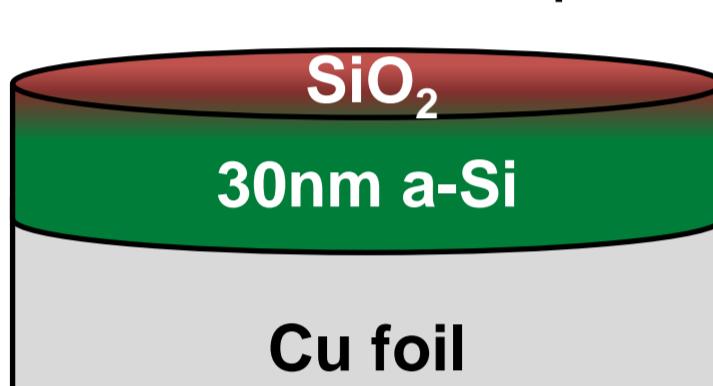
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Motivation

Electrochemical and surface analysis (XPS) of 30nm amorphous n-type Si thin films (a-Si) free of additives (carbon, binder) as model electrode

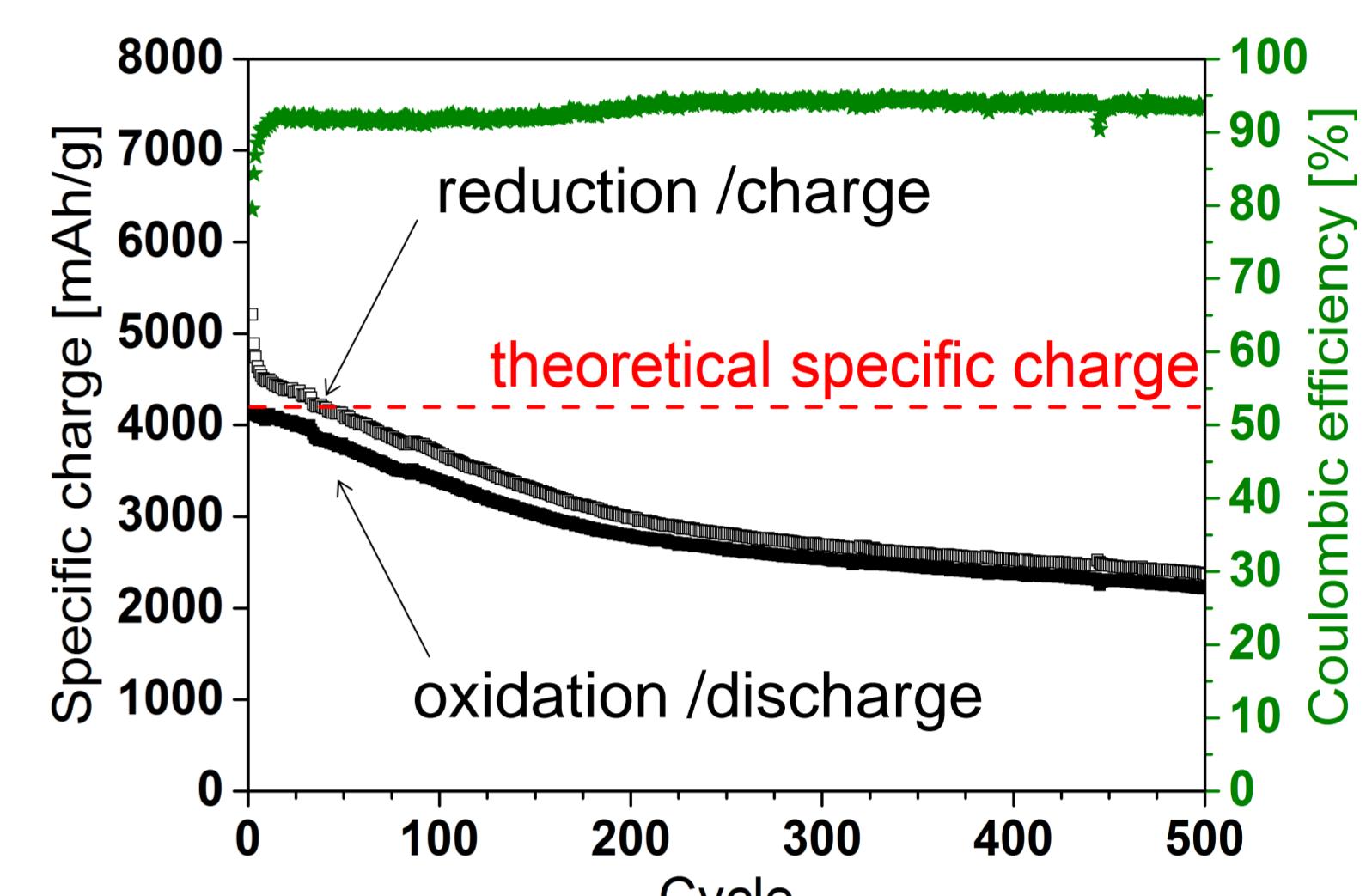
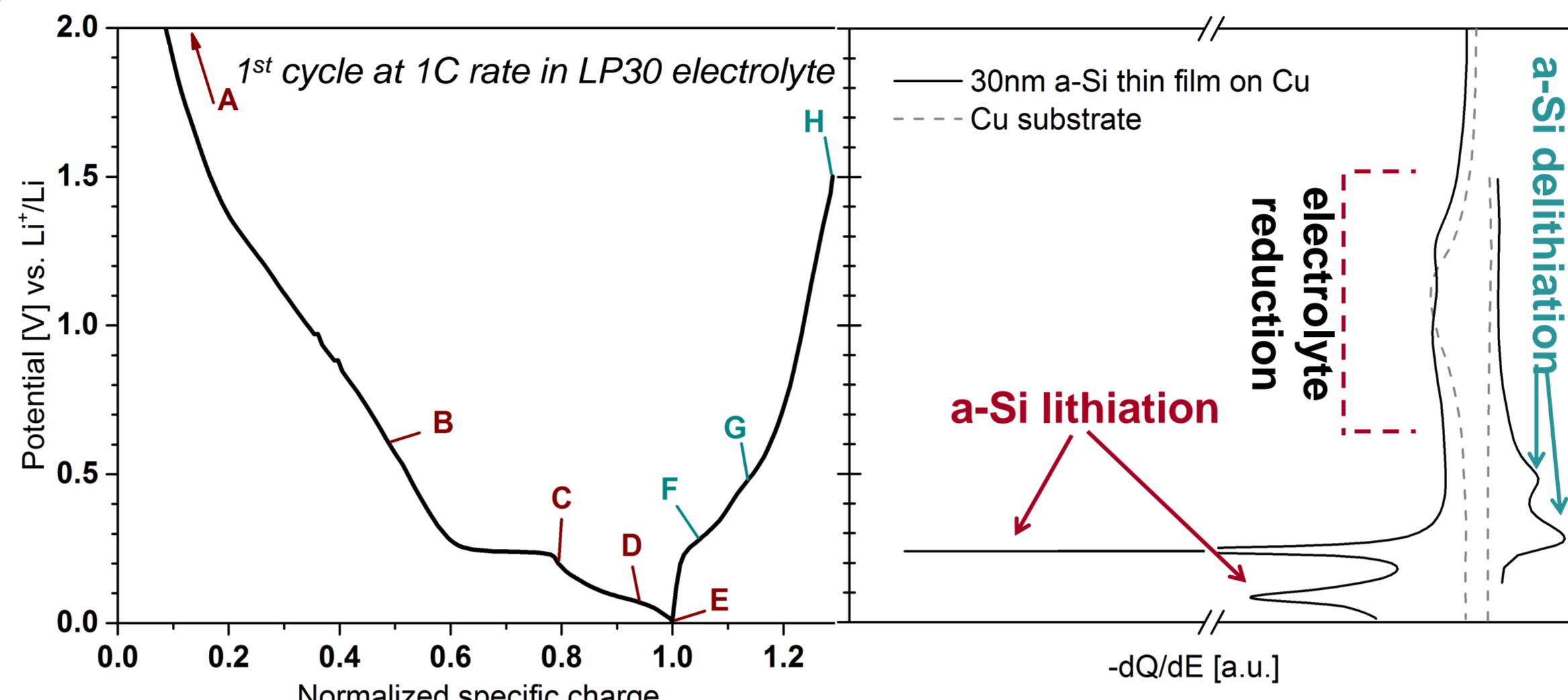
Open questions:

- Partial Si lithiation + Li-silicate irreversibility
- Reduction potentials of LP30 on a-Si thin film
- SEI composition and stability during 1st cycle



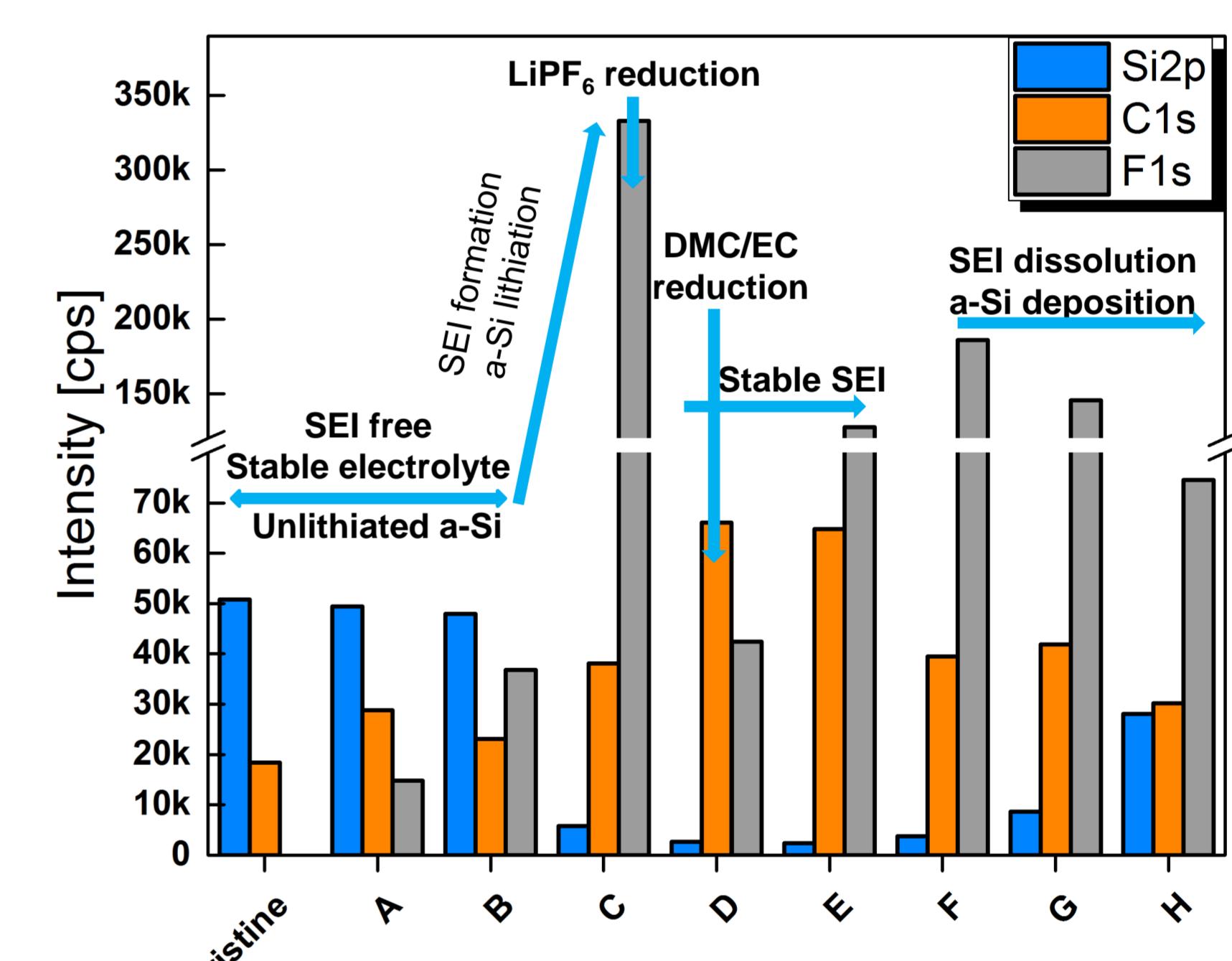
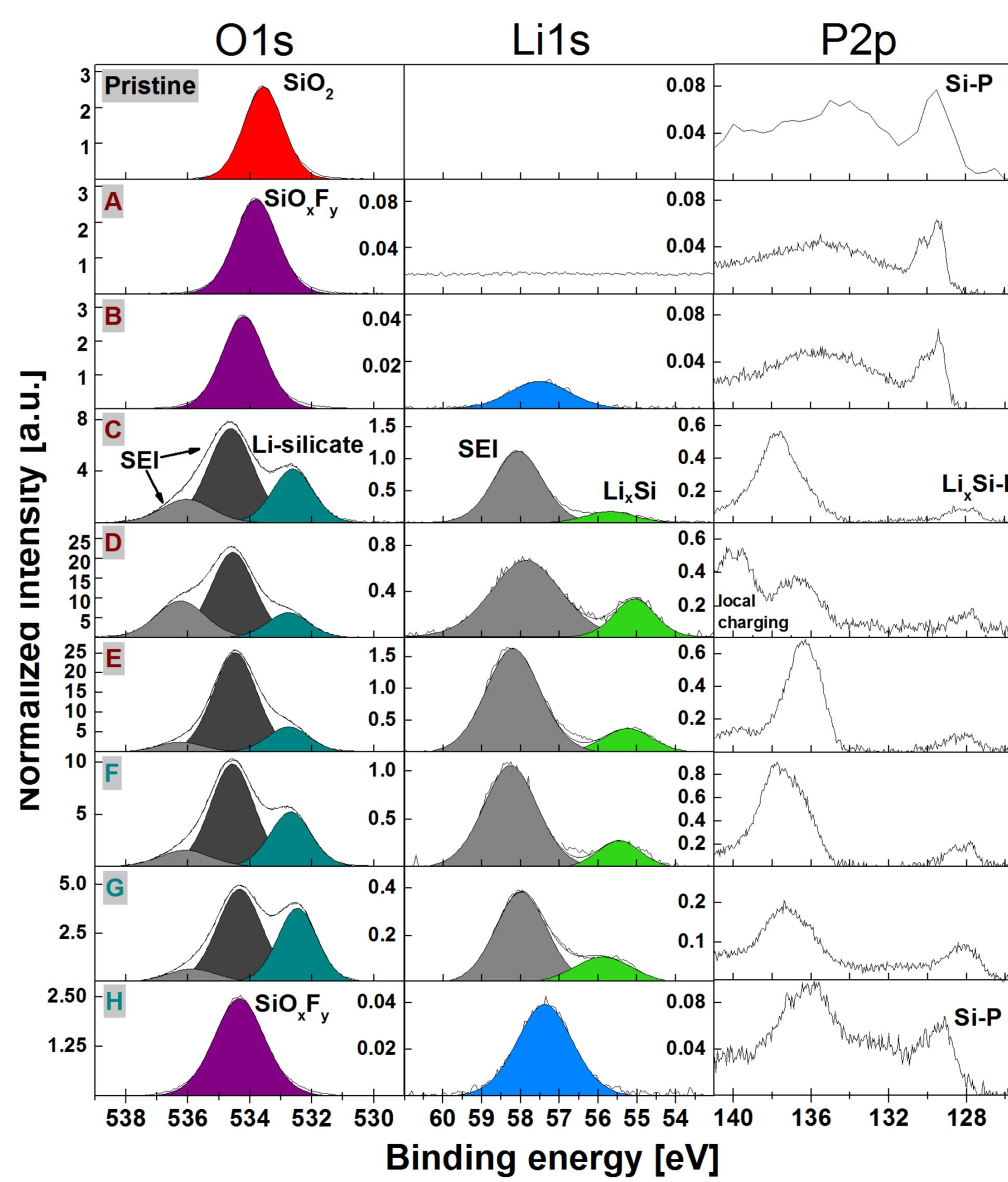
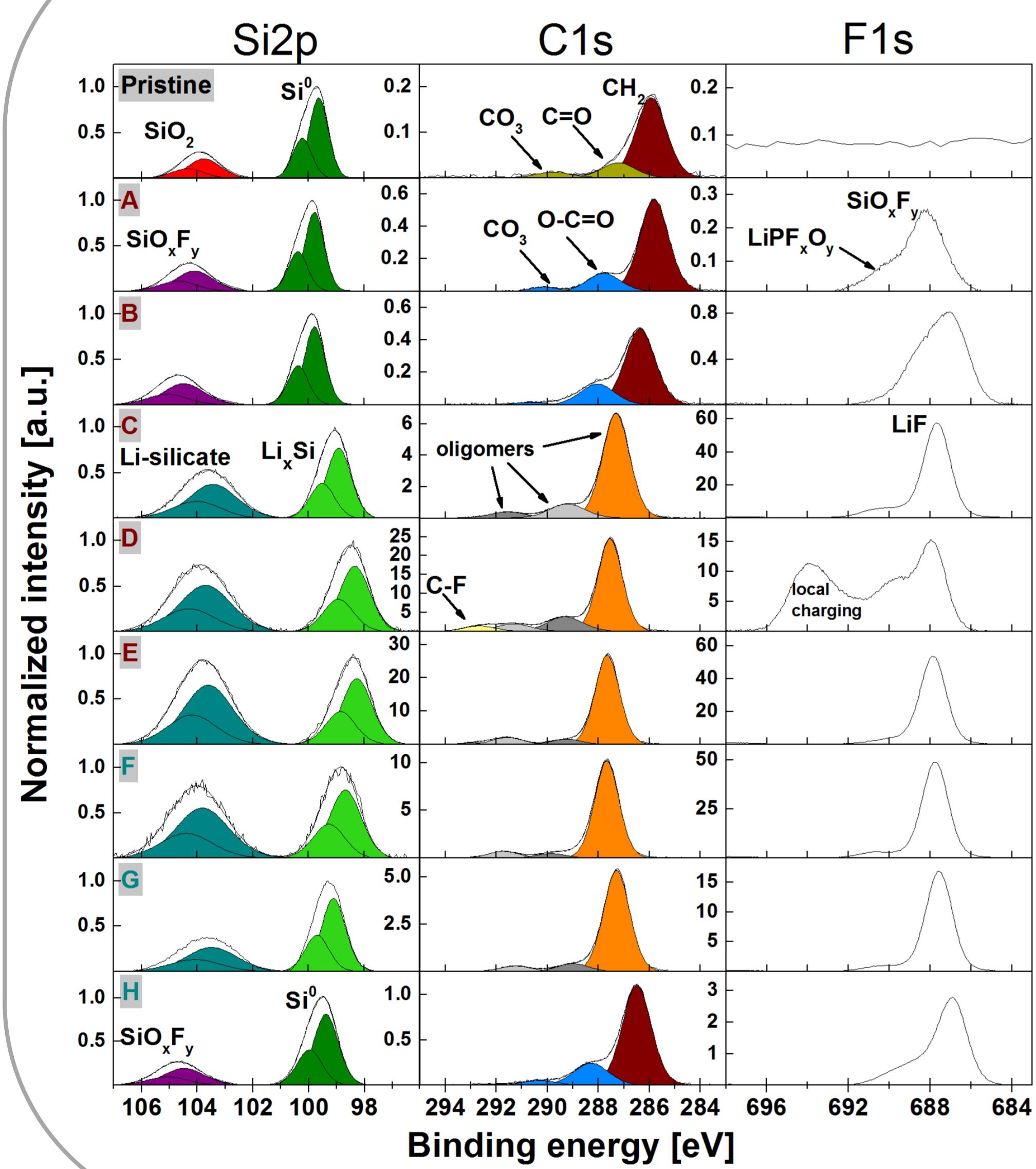
Model material:
30nm phosphorous-doped a-Si thin film on Cu foil
Technique: PECVD deposition
No binder, no conductive agent

Galvanostatic cycles



- Elevated irreversible charge consumption (electrolyte decomposition)
- 50% initial specific charge after 500 cycles

Post mortem XPS investigation



Charge

A-B → No SEI formation, no electrochemical reaction involving a-Si film

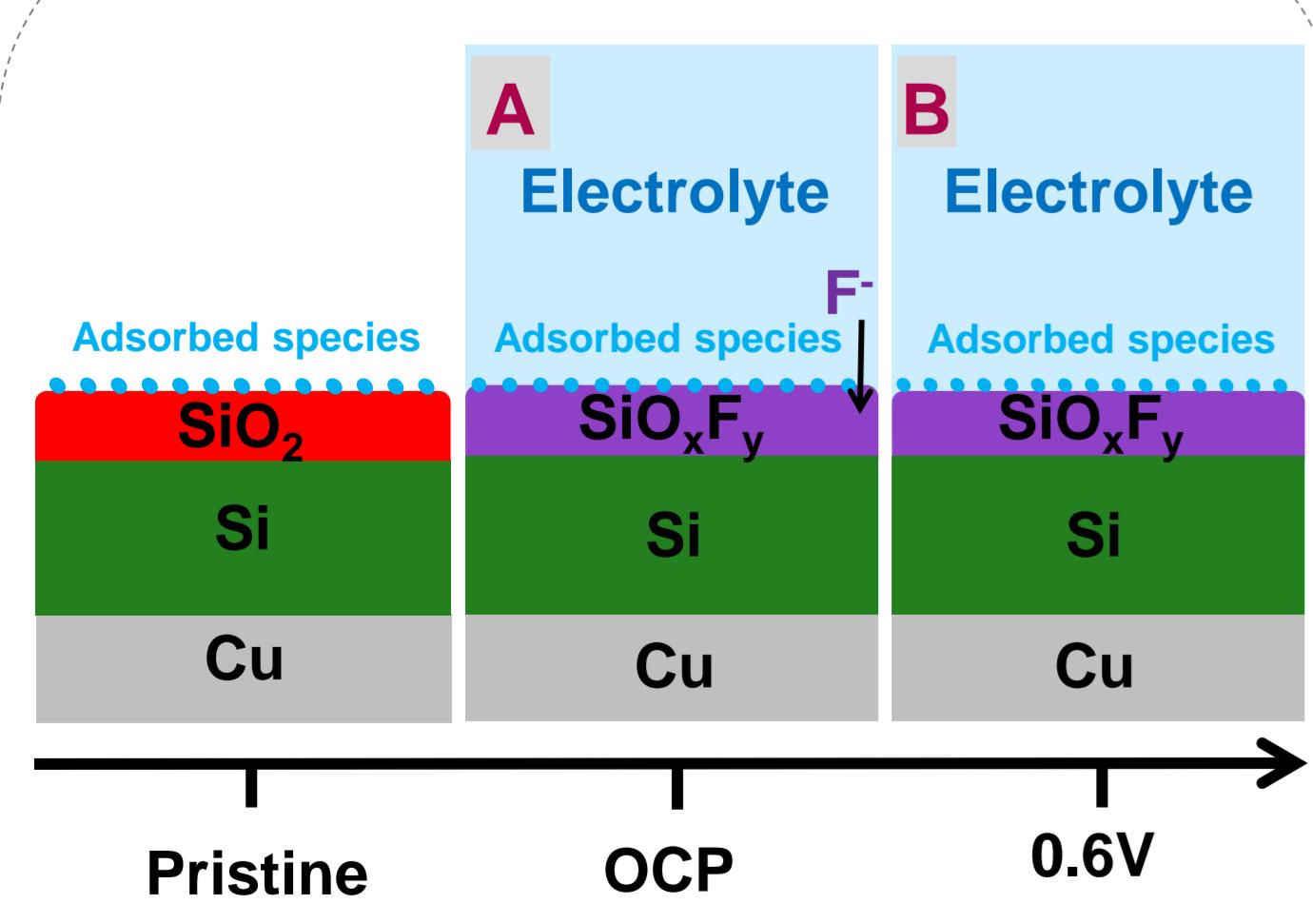
C-D-E → Li-silicate and Li_xSi alloy reactions, voltage-dependent SEI growth (at 0.2 V LiF clusters; at 0.07 V oligomeric matrix)

Discharge

F-G-H → Li_xSi and Li-silicate delithiation, SEI dissolution, partial loss of native oxide layer

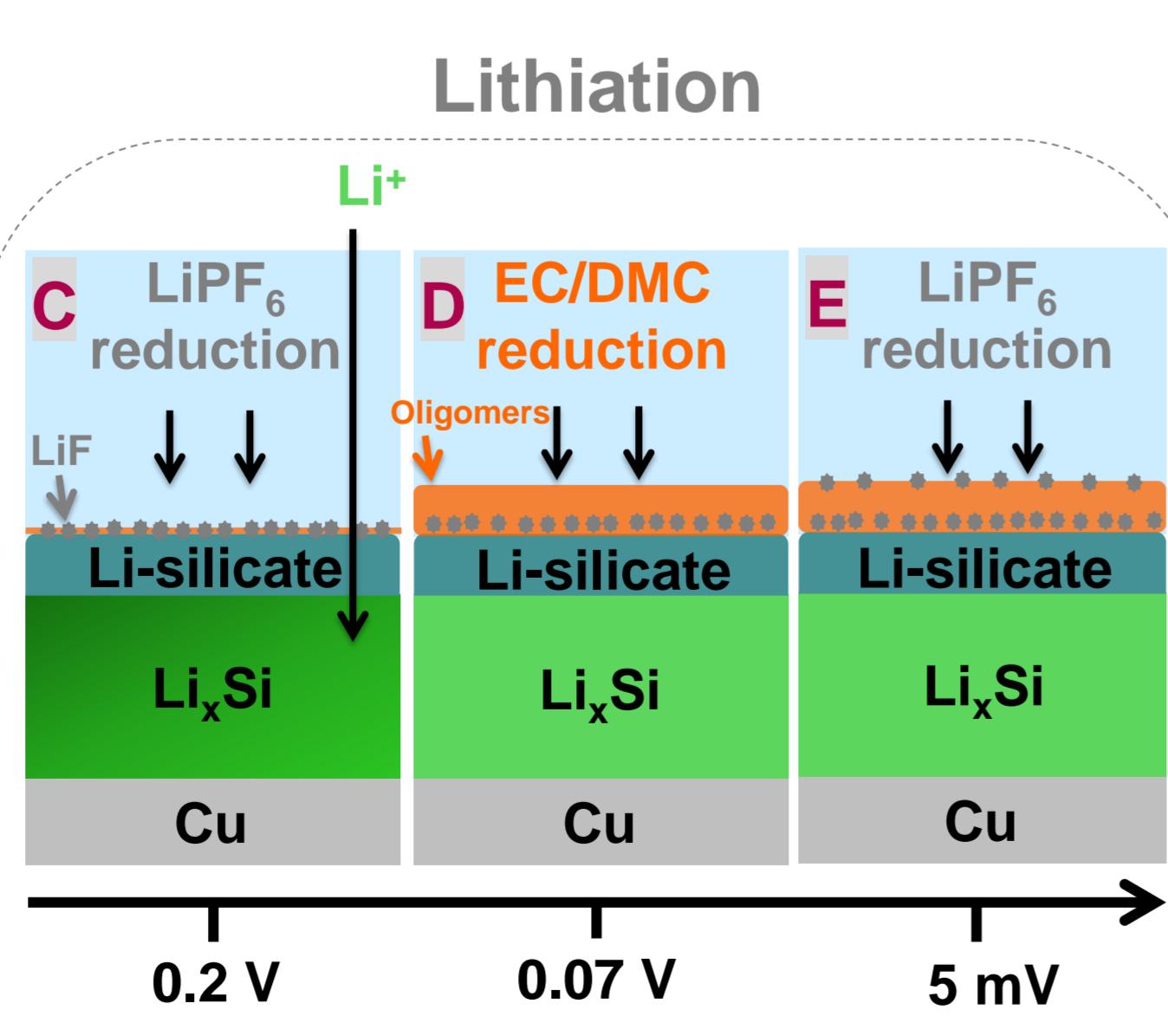
Reaction mechanism

Unlithiated a-Si – No SEI



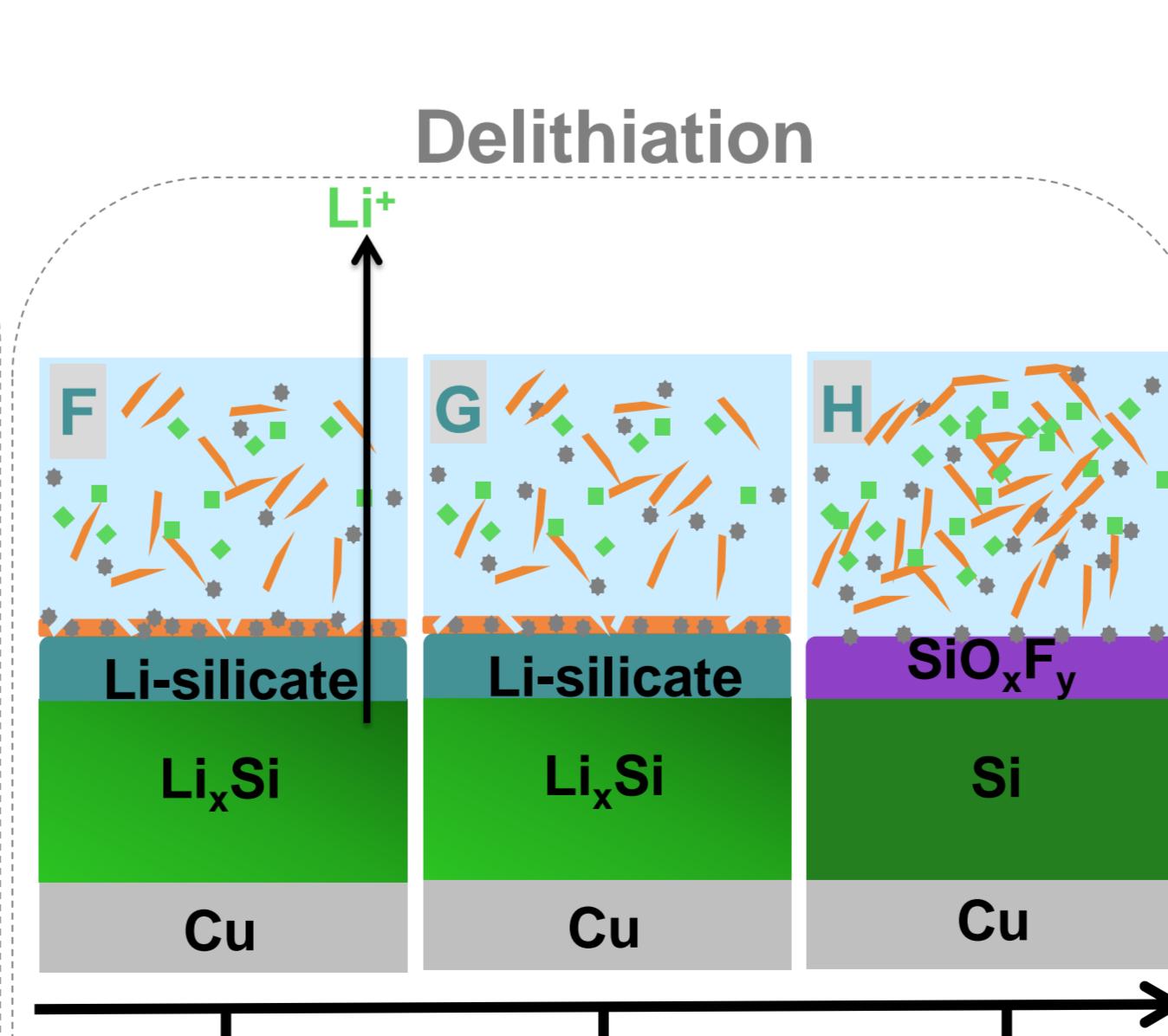
- Adsorbed species are oxidised in contact with LP30 electrolyte
- F⁻ (from LiPF₆) diffuses inside SiO₂ forming SiO_xF_y
- No SEI formation at 0.6 V is detected

Lithiation



- xLi + Si → Li_xSi multi-step reaction
- Li-silicate formation
- Voltage-dependent SEI formation: 0.2V → LiF (LiPF₆ reduction), 0.07V → oligomers (EC/DMC reduction), 5mV → mainly LiF clusters (LiPF₆)

Delithiation



- Reversible delithiation of Li_xSi and SiO_xN_y
- Li-silicate thickness is reduced
- SEI decomposition and dissolution

Conclusions/Outlook

- In-house XPS on Si2p, C1s, Li1s, O1s, F1s and P2p core levels to monitor SEI and Li-Si alloy reactions
- No SEI at voltage higher than 0.6V during charge
- Voltage-dependent SEI formation: at 0.2V LiPF₆ is formed, at 0.07V oligomers form from EC/DMC reduction
- SiO_xN_y lithiation is reversible at the end of delithiation
- Model reaction mechanism to elucidate the SEI growth mechanism and Li-Si alloy formation
- XPS on long-term cycling will shed the light on SEI stability and Li_xSi alloy reversibility

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